



3.3V CMOS 20-BIT UNIVERSAL BUS DRIVER WITH 3-STATE OUTPUTS

IDT74ALVC16836

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical $t_{sk(0)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model (C = 200pF, R = 0)
- 0.635mm pitch SSOP, 0.50mm pitch TSSOP,
and 0.40mm pitch TVSOP packages
- Extended commercial range of -40°C to $+85^{\circ}\text{C}$
- $V_{CC} = 3.3\text{V} \pm 0.3\text{V}$, Normal Range
- $V_{CC} = 2.7\text{V}$ to 3.6V , Extended Range
- $V_{CC} = 2.5\text{V} \pm 0.2\text{V}$
- CMOS power levels ($0.4\mu\text{W}$ typ. static)
- Rail-to-Rail output swing for increased noise margin

Drive Features for ALVC16836:

- High Output Drivers: $\pm 24\text{mA}$
- Suitable for heavy loads

DESCRIPTION:

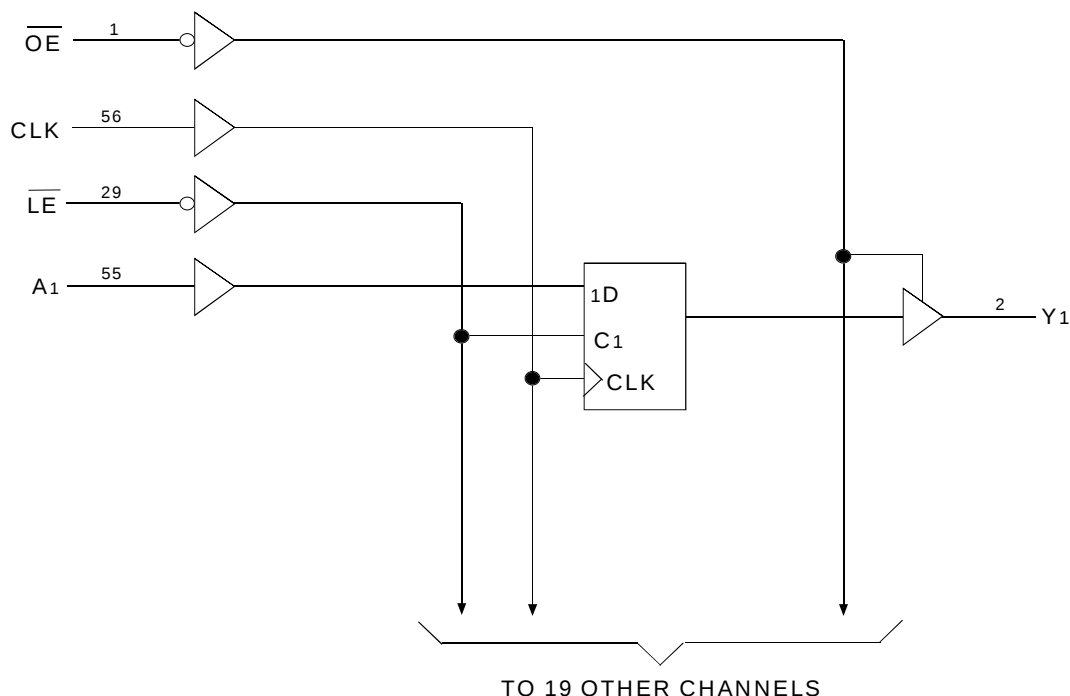
This 20-bit universal bus driver is built using advanced dual metal CMOS technology. Data flow from A to Y is controlled by the output-enable ($\overline{\text{OE}}$) input. The device operates in the transparent mode when the latch-enable ($\overline{\text{LE}}$) input is low. The A data is latched if the clock (CLK) input is held at a high or low logic level. If $\overline{\text{LE}}$ is high, the A data is stored in the latch flip-flop on the low-to-high transition of CLK. When $\overline{\text{OE}}$ is high, the outputs are in the high-impedance state.

The ALVC16836 has been designed with a $\pm 24\text{mA}$ output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

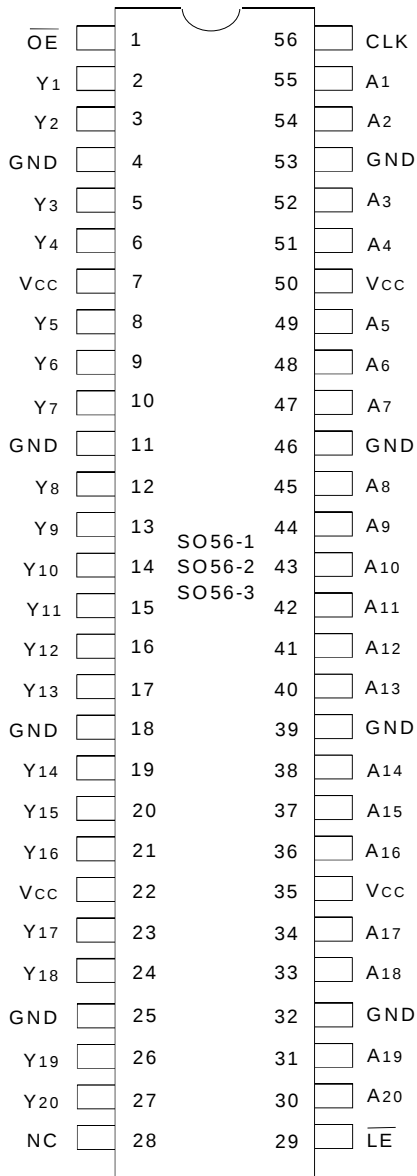
APPLICATIONS:

- SDRAM Modules
- PC Motherboards
- Workstations

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



SSOP/
TSSOP/ TVSOP
TOP VIEW

PIN DESCRIPTION

Pin Names	Description
$\overline{OE}$	3-State Output Enable Inputs (Active LOW)
CLK	Register Input Clock
$\overline{LE}$	Latch Enable (Active LOW)
Ax	Data Inputs
Yx	3-State Outputs
NC	No Internal Connection

ABSOLUTE MAXIMUM RATING (1)

Symbol	Description	Max.	Unit
$V_{TERM}^{(2)}$	Terminal Voltage with Respect to GND	- 0.5 to + 4.6	V
$V_{TERM}^{(3)}$	Terminal Voltage with Respect to GND	- 0.5 to $V_{CC} + 0.5$	V
TSTG	Storage Temperature	- 65 to + 150	°C
I _{OUT}	DC Output Current	- 50 to + 50	mA
I _{IK}	Continuous Clamp Current, $V_I < 0$ or $V_I > V_{CC}$	± 50	mA
I _{OK}	Continuous Clamp Current, $V_O < 0$	- 50	mA
I _{CC}	Continuous Current through each Vcc or GND	±100	mA

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NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- Vcc terminals.
- All terminals except Vcc.

CAPACITANCE ($T_A = +25^\circ\text{C}$, $f = 1.0\text{MHz}$)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	$V_{IN} = 0V$	5	7	pF
C _{OUT}	Output Capacitance	$V_{OUT} = 0V$	7	9	pF
C _{I/O}	I/O Port Capacitance	$V_{IN} = 0V$	7	9	pF

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NOTE:

- As applicable to the device type.

FUNCTION TABLE⁽¹⁾

Inputs				Outputs
$\overline{OE}$	$\overline{LE}$	CLK	Ax	Yx
H	X	X	X	Z
L	L	X	L	L
L	L	X	H	H
L	H	↑	L	L
L	H	↑	H	H
L	H	H	X	Y_0
L	H	L	X	Y_0

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High-Impedance
- = LOW-to-HIGH Transition
 Y_0 = Output level before the indicated steady-state input conditions were established

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	VCC = 2.3V to 2.7V		1.7	—	—	V
		VCC = 2.7V to 3.6V		2	—	—	
VIL	Input LOW Voltage Level	VCC = 2.3V to 2.7V		—	—	0.7	V
		VCC = 2.7V to 3.6V		—	—	0.8	
IiH	Input HIGH Current	VCC = 3.6V	Vi = VCC	—	—	± 5	μA
IiL	Input LOW Current	VCC = 3.6V	Vi = GND	—	—	± 5	
IozH	High Impedance Output Current (3-State Output pins)	VCC = 3.6V	Vo = VCC	—	—	± 10	μA
IozL			Vo = GND	—	—	± 10	μA
VIK	Clamp Diode Voltage	VCC = 2.3V, IIN = -18mA		—	-0.7	-1.2	V
VH	Input Hysteresis	VCC = 3.3V		—	100	—	mV
ICCL ICCH ICcz	Quiescent Power Supply Current	VCC = 3.6V VIN = GND or VCC		—	0.1	40	μA
ΔICC	Quiescent Power Supply Current Variation	One input at VCC - 0.6V, other inputs at VCC or GND		—	—	750	μA

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NOTE:

- Typical values are at VCC = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage	VCC = 2.3V to 3.6V	IOH = -0.1mA	VCC - 0.2	—	V
		VCC = 2.3V	IOH = -6mA	2	—	
		VCC = 2.3V	IOH = -12mA	1.7	—	
		VCC = 2.7V		2.2	—	
		VCC = 3.0V		2.4	—	
		VCC = 3.0V	IOH = -24mA	2	—	
VOL	Output LOW Voltage	VCC = 2.3V to 3.6V	IOL = 0.1mA	—	0.2	V
		VCC = 2.3V	IOL = 6mA	—	0.4	
			IOL = 12mA	—	0.7	
		VCC = 2.7V	IOL = 12mA	—	0.4	
		VCC = 3.0V	IOL = 24mA	—	0.55	

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NOTE:

- VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate VCC range. TA = -40°C to +85°C.

OPERATING CHARACTERISTICS, $T_A = 25^{\circ}\text{C}$

Symbol	Parameter	Test Conditions	$V_{CC} = 2.5V \pm 0.2V$	$V_{CC} = 3.3V \pm 0.3V$	Unit
			Typical	Typical	
CPD	Power Dissipation Capacitance Outputs enabled	$C_L = 0\text{pF}$, $f = 10\text{MHz}$	—	—	pF
CPD	Power Dissipation Capacitance Outputs disabled		—	—	pF

SWITCHING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 2.7V$		$V_{CC} = 3.3V \pm 0.3V$		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
f_{MAX}		150	—	150	—	150	—	MHz
t_{PLH} t_{PHL}	Propagation Delay Ax to Yx	1	4.2	—	4.2	1	3.6	ns
t_{PLH} t_{PHL}	Propagation Delay LE to Yx	1.3	5	—	4.9	1.3	4.2	ns
t_{PLH} t_{PHL}	Propagation Delay CLK to Yx	1.4	5.5	—	5.2	1.4	4.5	ns
t_{PZH} t_{PZL}	Output Enable Time OE to Yx	1.4	5.5	—	5.6	1.1	4.6	ns
t_{PHZ} t_{PLZ}	Output Disable Time OE to Yx	1	4.5	—	4.3	1.3	3.9	ns
t_w	Pulse Duration, LE LOW	3.3	—	3.3	—	3.3	—	ns
t_w	Pulse Duration, CLK HIGH or LOW	3.3	—	3.3	—	3.3	—	ns
t_{SU}	Setup Time, data before CLK $\uparrow$	1.4	—	1.7	—	1.5	—	ns
t_{SU}	Setup Time, data before LE $\uparrow$, CLK HIGH	1.2	—	1.6	—	1.3	—	ns
t_{SU}	Setup Time, data before LE $\uparrow$, CLK LOW	1.4	—	1.5	—	1.2	—	ns
t_H	Hold Time, data after CLK $\uparrow$	0.9	—	0.9	—	0.9	—	ns
t_H	Hold Time, data after LE $\uparrow$, CLK HIGH or LOW	1.1	—	1.1	—	1.1	—	ns
$t_{sk(0)}$	Output Skew ⁽²⁾	—	—	—	—	—	500	ps

NOTES:

1. See test circuits and waveforms. $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$.
2. Skew between any two outputs of the same package and switching in the same direction.

SWITCHING CHARACTERISTICS FROM 0°C TO 65°C , $C_L = 50\text{ pF}$

Symbol	Parameter	$V_{CC} = 3.3V \pm 0.15V$		Unit
		Min.	Max.	
t_{PLH} t_{PHL}	Propagation Delay CLK to Yx	—	—	ns

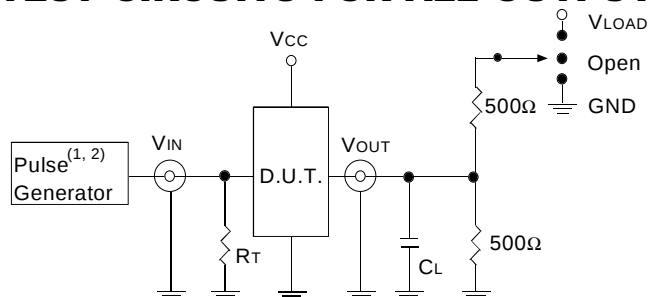
TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	V _{CC} (1)= 3.3V±0.3V	V _{CC} (1)= 2.7V	V _{CC} (2)= 2.5V±0.2V	Unit
V _{LOAD}	6	6	2 x V _{CC}	V
V _{IH}	2.7	2.7	V _{CC}	V
V _T	1.5	1.5	V _{CC} / 2	V
V _{LZ}	300	300	150	mV
V _{HZ}	300	300	150	mV
C _L	50	50	30	pF

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TEST CIRCUITS FOR ALL OUTPUTS



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DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.

R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

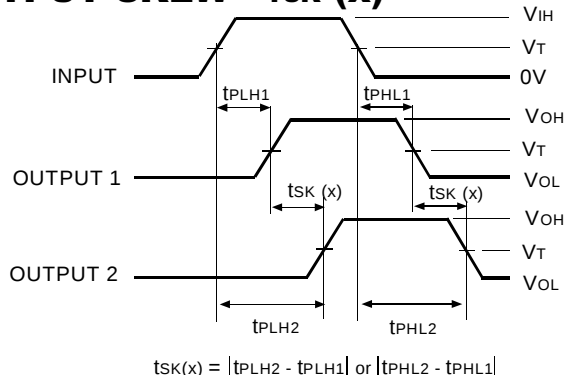
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	V _{LOAD}
Disable High Enable High	GND
All Other tests	Open

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OUTPUT SKEW - t_{SK} (x)



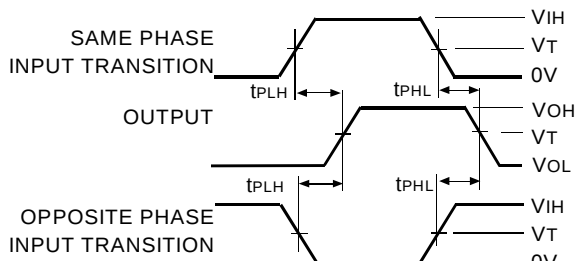
$$t_{SK}(x) = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

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NOTES:

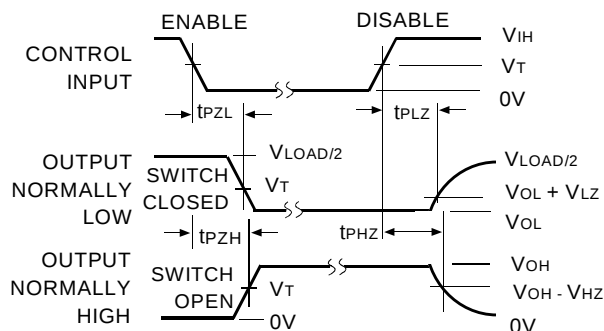
1. For t_{SK}(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t_{SK}(b) OUTPUT1 and OUTPUT2 are in the same bank.

PROPAGATION DELAY



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ENABLE AND DISABLE TIMES

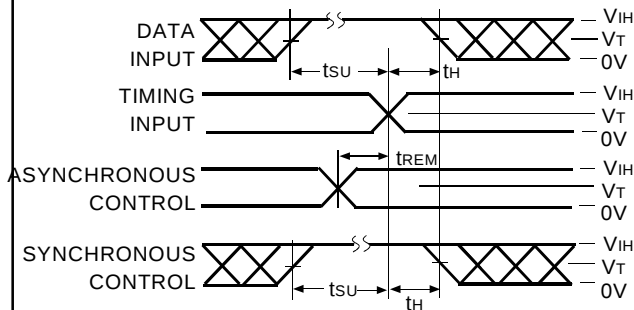


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NOTE:

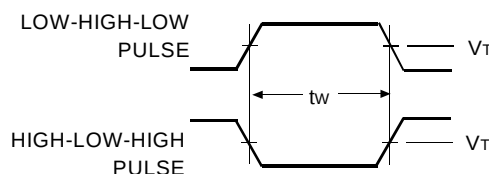
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD, AND RELEASE TIMES



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PULSE WIDTH



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ORDERING INFORMATION

IDT	XX	ALVC	X	XX	XXX	XX	
	Temp. Range		Bus-Hold	Family	Device Type	Package	
						PV	Shrink Small Outline Package (SO56-1)
						PA	Thin Shrink Small Outline Package (SO56-2)
						PF	Thin Very Small Outline Package (SO56-3)
						836	20-Bit Universal Bus Driver with 3-State Outputs
						16	Double-Density with Resistors, $\pm 24\text{mA}$
						Blank	No Bus-Hold
						74	-40°C to $+85^{\circ}\text{C}$



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